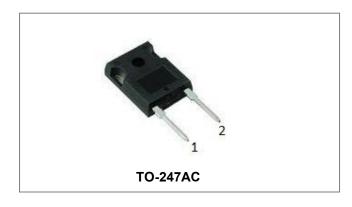


Technical Data Data Sheet N1270, Rev. B





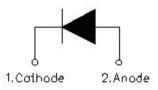
# SDUR6030W ULTRAFAST RECTIFIER



# **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## **Circuit Diagram**



#### **Features**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	300	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=105°C, rectangular wave form	60	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	450	А

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 60A, Pulse, T <sub>J</sub> = 25°C	-	1.40	V
	$V_{F2}$	@ 60A, Pulse, T <sub>J</sub> = 150°C	-	1.10	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$	-	10	μΑ
	I <sub>R2</sub>	$@V_R = \text{ rated } V_R$ $T_J = 125^{\circ}C$	-	350	uA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>rm</sub> =250mA	-	45	ns

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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Technical Data Data Sheet N1270, Rev. B

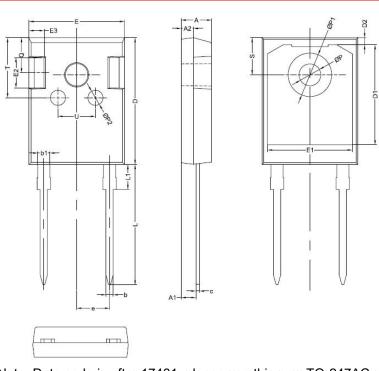




# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.54	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

## **Mechanical Dimensions TO-247AC**



SYMBOL	Millimeters				
STIVIBUL	MIN.	TYP.	MAX.		
Α	4.80	5.00	5.20		
A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.35		
b1	1.80	2.00	2.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.58			
D2		1.17			
E	15.60	15.80	16.00		
E1		14.02			
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.42		
L1		4.13			
P	3.50	3.60	3.70		
<u>P1</u>	7.1	7.19	7.40		
P2		2.50			
Q		5.80			
Ŝ	6.05	6.15	6.25		
T		10.00			
U		6.20			
Α	4.80	5.00	5.20		
A1	2.20	2.41	2.61		

Note: Date code is after 17481, please use this new TO-247AC mechanical dimensions.

## **Tube Specification**

# 12mm 510mm

## **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type 60 = Forward Current (60A) 30 = Reverse Voltage (300V) W = Configuration

SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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#### Technical Data Data Sheet N1270, Rev. B





#### **Ordering Information**

Device	Package	Shipping	
SDUR6030W	TO-247AC(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
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